

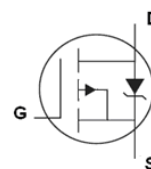
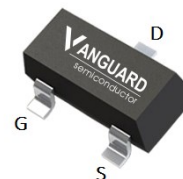
Features

- P-Channel
- Enhancement mode
- Fast Switching
- Pb-free lead plating; RoHS compliant

V_{DS}	-30	V
$R_{DS(on),max} @ V_{GS} = -10V$	52	mΩ
$R_{DS(on),max} @ V_{GS} = -4.5V$	62	mΩ
I_D	-3.4	A


Halogen-Free

Part ID	Package Type	Marking	Tape and reel information
VS3540AC	SOT23	VS01	3000pcs/reel

SOT23


Maximum ratings, at $T_J = 25^\circ\text{C}$, unless otherwise specified

Symbol	Parameter	Rating	Unit
$V_{(BR)DSS}$	Drain-Source breakdown voltage	-30	V
I_S	Diode continuous forward current	$T_A = 25^\circ\text{C}$ -1.2	A
I_D	Continuous drain current @ $V_{GS} = -4.5V$	$T_A = 25^\circ\text{C}$ -3.4	A
		$T_A = 70^\circ\text{C}$ -2.7	A
I_{DM}	Pulse drain current tested ①	$T_A = 25^\circ\text{C}$ 12	A
P_D	Maximum power dissipation	$T_A = 25^\circ\text{C}$ 1	W
V_{GS}	Gate-Source voltage	± 12	V
$T_{STG} T_J$	Storage and operating temperature range	-55 to 150	$^\circ\text{C}$
Thermal Characteristics			
$R_{\theta JL}$	Thermal Resistance-Junction to Lead	80	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	125	$^\circ\text{C/W}$

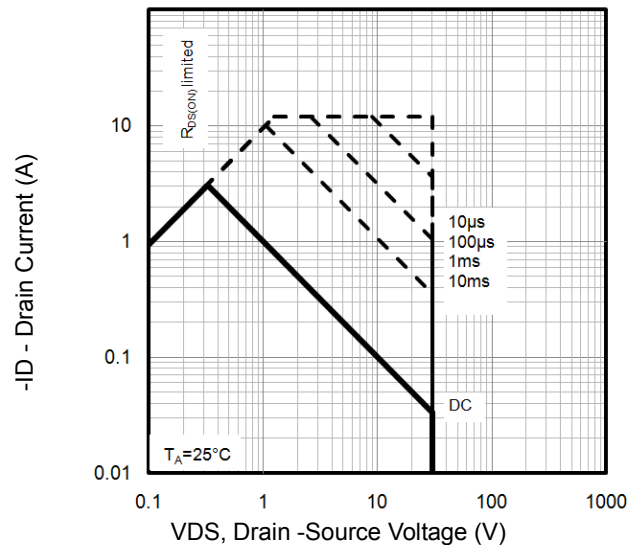
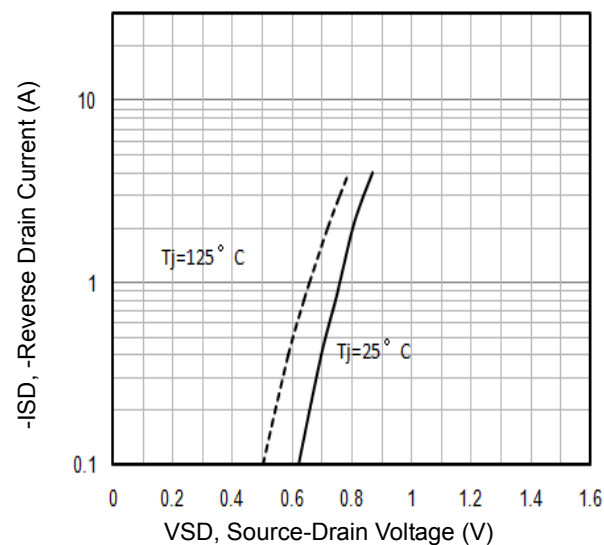
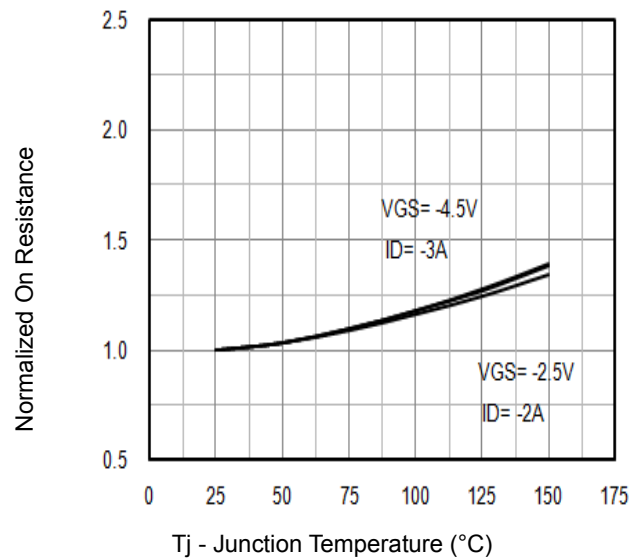
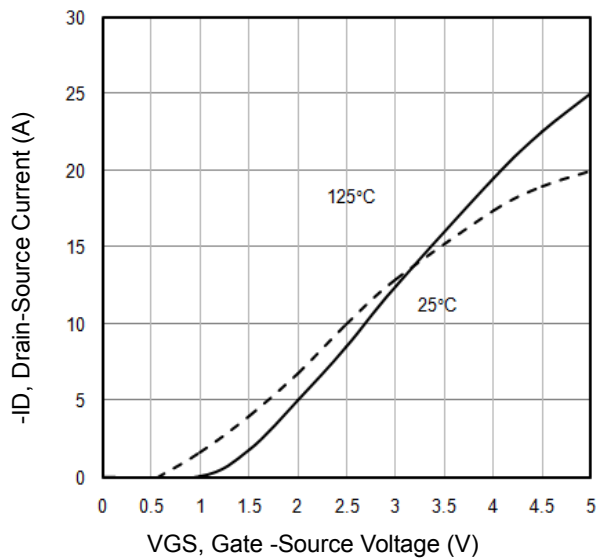
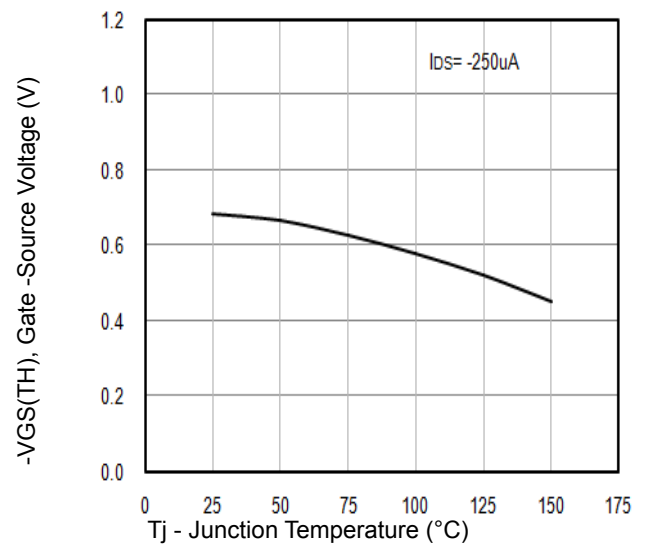
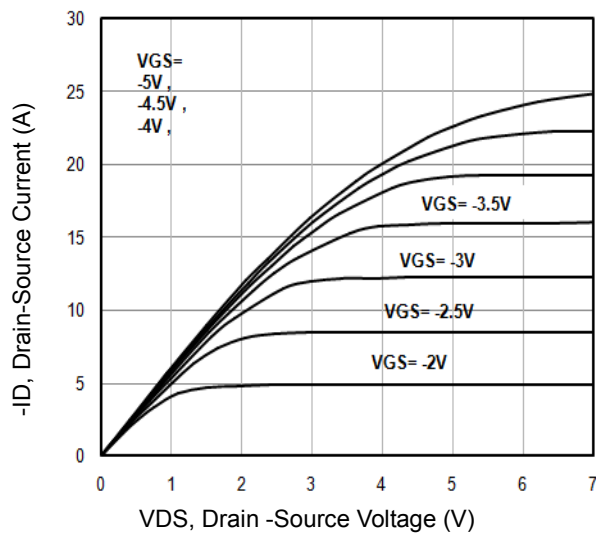
Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
Static Electrical Characteristics @ T _j = 25°C (unless otherwise stated)						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =-250μA	-30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current(T _j =25°C)	V _{DS} =-30V,V _{GS} =0V	--	--	1	μA
	Zero Gate Voltage Drain Current(T _j =125°C)	V _{DS} =-30V,V _{GS} =0V	--	--	100	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±12V,V _{DS} =0V	--	--	±100	nA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} =V _{GS} ,I _D =-250μA	-0.5	--	-1.2	V
R _{DS(ON)}	Drain-Source On-State Resistance②	V _{GS} =-10V, I _D =-4A	--	52	60	mΩ
		V _{GS} =-4.5V, I _D =-3A	--	62	70	mΩ
		V _{GS} =-2.5V, I _D =-2A	--	81	105	mΩ
Dynamic Electrical Characteristics @ T _j = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =-15V,V _{GS} =0V, f=1MHz	--	805	--	pF
C _{oss}	Output Capacitance		--	60	--	pF
C _{rss}	Reverse Transfer Capacitance		--	50	--	pF
R _g	Gate Resistance	f=1MHz	--	10	--	Ω
Q _g	Total Gate Charge	V _{DS} =-15V,I _D =-4A, V _{GS} =-4.5V	--	10	--	nC
Q _{gs}	Gate-Source Charge		--	2.3	--	nC
Q _{gd}	Gate-Drain Charge		--	4.2	--	nC
Switching Characteristics						
t _{d(on)}	Turn-on Delay Time	V _{DD} =-15 V, I _D =-4A, R _G =3Ω, V _{GS} =-4.5V	--	4	--	nS
t _r	Turn-on Rise Time		--	4	--	nS
t _{d(off)}	Turn-Off Delay Time		--	28	--	nS
t _f	Turn-Off Fall Time		--	4.6	--	nS
Source- Drain Diode Characteristics@ T _j = 25°C (unless otherwise stated)						
V _{SD}	Forward on voltage	I _{SD} =-3A,V _{GS} =0V	--	-0.85	-1.2	V
t _{rr}	Reverse Recovery Time	T _j =25°C,I _{sd} =-3A, V _{GS} =0V	--	12	--	nS
Q _{rr}	Reverse Recovery Charge	di/dt=-100A/μs		3.6		nC

NOTE:

- ① Repetitive rating; pulse width limited by max. junction temperature.
 ② Pulse width ≤ 300μs; duty cycles ≤ 2%.



Typical Characteristics



Typical Characteristics

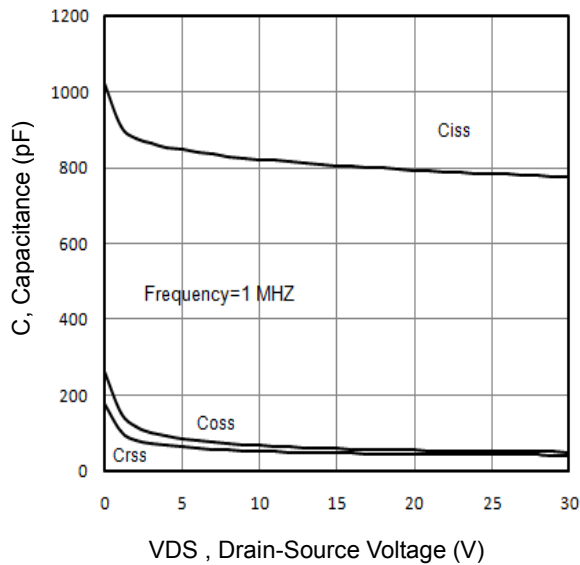


Fig7. Typical Capacitance Vs. Drain-Source Voltage

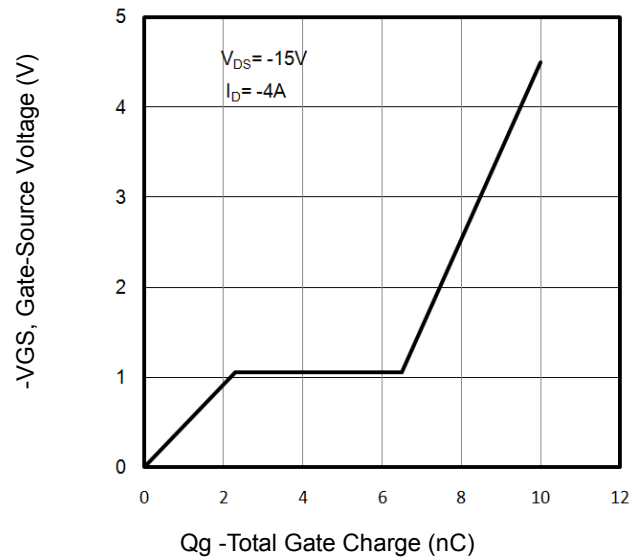


Fig8. Typical Gate Charge Vs. Gate-Source Voltage

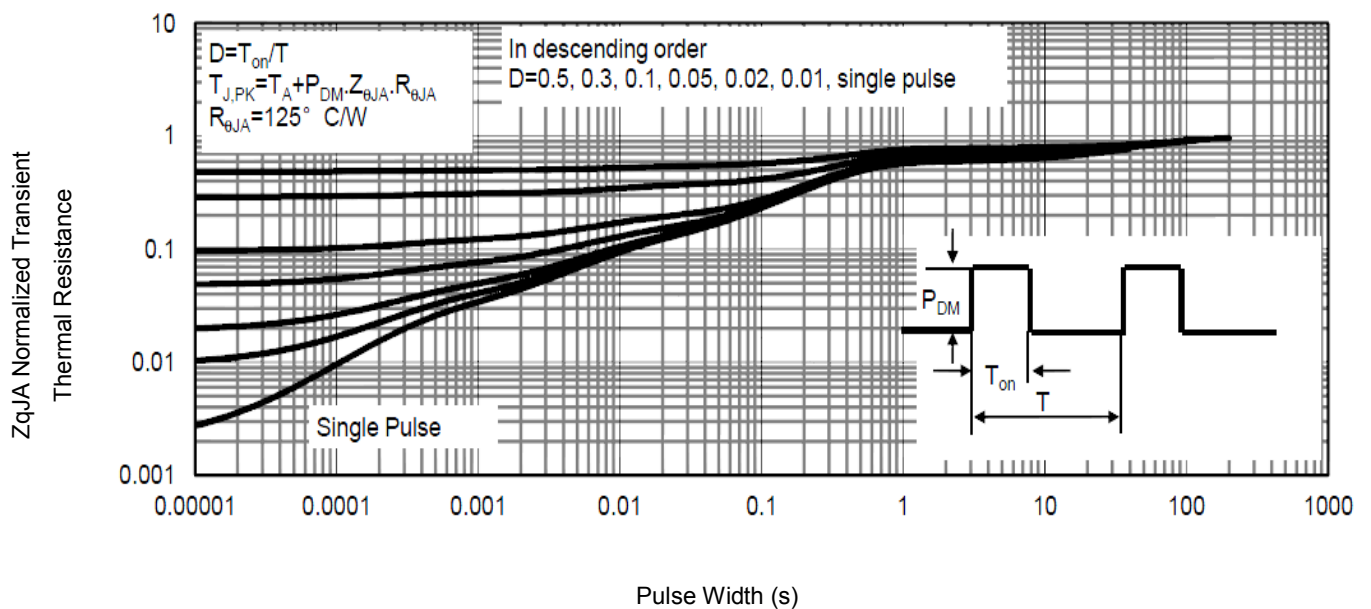


Fig9. Normalized Maximum Transient Thermal Impedance

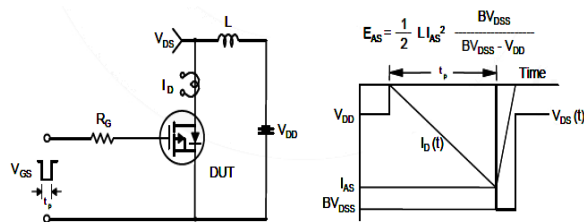


Fig10. Unclamped Inductive Test Circuit and waveforms

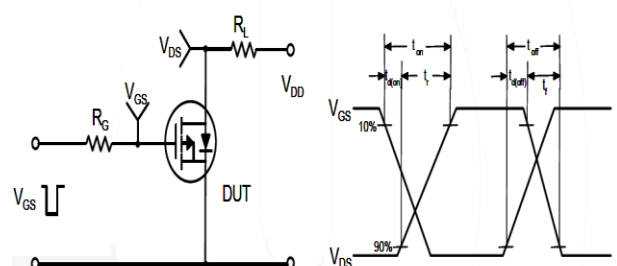
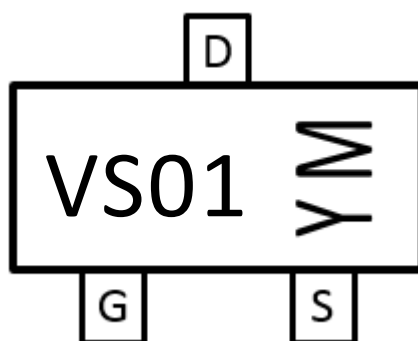


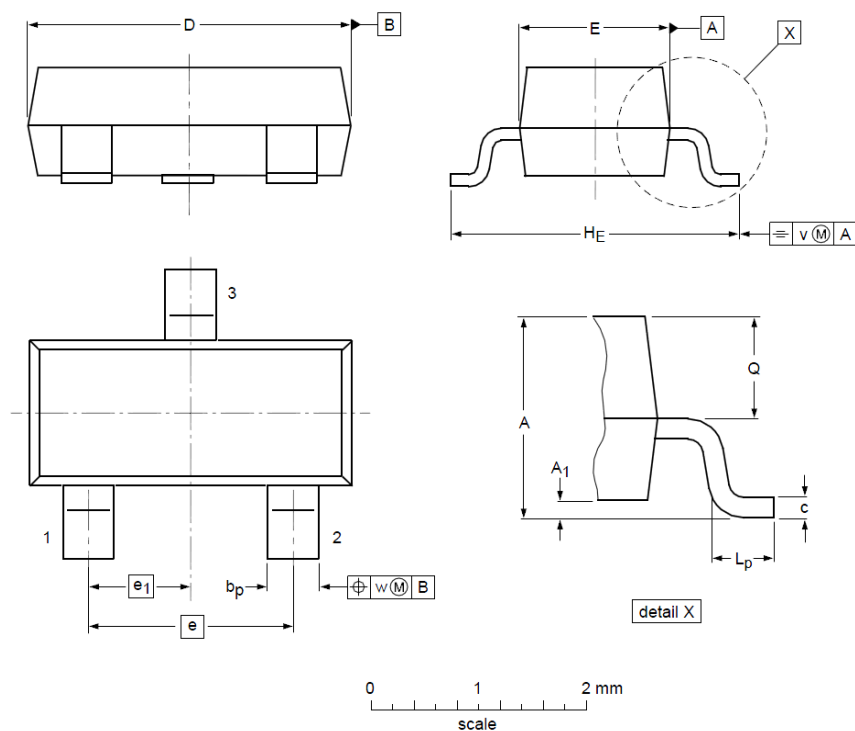
Fig11. Switching Time Test Circuit and waveforms

Marking Information

VS01: Part Number

YM: Date Code, Y means assembly year, M means assembly month

SOT23 Package Outline Data



Label	DIMENSIONS (unit: mm)		
	Min	Typ	Max
A	0.90	1.03	1.10
A₁	0.01	0.05	0.10
b_p	0.38	0.42	0.48
c	0.09	0.13	0.15
D	2.80	2.92	3.00
E	1.20	1.33	1.40
e	--	1.90	--
e₁	--	0.95	--
H_E	2.10	2.40	2.50
L_p	0.40	0.50	0.60
Q	0.45	0.49	0.55
v	--	0.20	--
w	--	0.10	--

Notes:

1. Follow JEDEC TO-236, variation AB.
2. Dimension "D" does NOT include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.25mm per side.
3. Dimension "E" does NOT include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25mm per side.

Customer Service

Sales and Service:

sales@vgsemi.com

Vanguard Semiconductor CO., LTD

TEL: (86-755) -26902410

FAX: (86-755) -26907027

WEB: www.vgsemi.com